TT 60: Frontiers of Electronic Structure Theory: Focus on Topology and Transport
(Joint session of DS, HL, MA, MM, O and TT organized by O)

Time: Wednesday 18:15–20:30   Location: Poster A

TT 60.1   Wed 18:15   Poster A

Improving anharmonic vibrational calculations from first principles — •Joseph C.A. Prentice, Bartomeu Monserrat, and Richard J. Needs — TCM Group, Cavendish Laboratory, University of Cambridge, UK

The vibrational self-consistent field (VSCF) method, as described in PRB 87 144302, has had several successes in accurately calculating the anharmonic properties of various materials, such as diamond, ice and solid hydrogen. However, a practical issue with the method is the large number of DFT calculations required to map the Born-Oppenheimer energy surface sufficiently accurately. We look at improvements to the method that reduce this computational load, in particular using data on forces from DFT calculations to improve the accuracy of the mapping. Results using this improved method are presented for competing structures of silicate perovskite under lower mantle conditions. Further improvements, involving the inclusion of n-body coupling between phonons, and their possible implementation are also discussed.

TT 60.2   Wed 18:15   Poster A

Towards a practical implementation of second-order Møller-Plesset perturbation theory for solids — •Xiangyue Liu, Arvid Conrad Ihrig, Sergey Levchenko, Igor Ying Zhang, and Matthias Scheffler — Fritz-Haber-Institut der MPG, Berlin, DE

The second-order Møller-Plesset perturbation theory (MP2) method is gaining attention in materials science, because it is free from the one-electron self-interaction error. Such error, as a lasting problem in density-functional theory, can lead to a wrong prediction of electronic band gaps, charge transfers, and reaction barriers, all of which are ubiquitous electronic properties or behaviors in condensed-matter systems. However, the unfavourable computational complexity, especially the cubic scaling with respect to the k-point number in reciprocal space, limits the applicability of MP2 for solids. In this project we present a practical MP2 implementation for solids in the all-electron full-potential framework. In our implementation, the MP2 correlation energy is evaluated in the atomic-orbital (AO) representation (AO-MP2), which allows for a lower computational scaling in both real and reciprocal spaces[1]. The localized resolution of identity (RI-LVL) technique[2] is adopted to address the memory bottleneck of the AO-MP2 method, making it feasible to handle systems with several hundred atoms per supercell while avoiding the reliance on the disk storage. We demonstrate the accuracy as well as the efficiency of our new MP2 implementation for a diverse set of materials. [1] Levchenko, S. V. *et al.*, Comput. Phys. Comm. **192**, 60, (2015); [2] Ihrig, A.C. *et al.*, New J. Phys. **17** 093020, (2015).

TT 60.3   Wed 18:15   Poster A

Application of the exact exchange functional to magnetic metals within the FLAPW method — •Max Nusspickel[1], Markus Betzinger[1], Christoph Friedrich[1], Andreas Görling[2], and Stefan Blügel[1] — [1]Peter Grünberg Institut and Institute for Advanced Simulation, Forschungszentrum Jülich and JARA, Germany — [2]Lehrstuhl für Theoretische Chemie, Universität Erlangen-Nürnberg, Germany

Orbital-dependent functionals form a promising class of exchange-correlation (xc) functionals in Kohn-Sham density-functional theory. Already the simplest functional of its kind, the exact exchange functional (EXX), cures the unphysical Coulomb self-interaction error of LDA and GGA functionals. In order to obtain a local xc potential from an orbital-dependent functional, the optimized effective potential (OEP) method is used, resulting in an integral equation for the potential. This equation, however, determines the potential only up to a constant.

In spin-polarized metals, the alignment of the spin-up and spin-down potentials is obtained by the requirement of electron number conservation: variations of the potential can lead to a change of the Fermi energy and, hence, to a variation of the densities of both electron spins. In this way, the OEP equations for the spin-up and spin-down potentials are coupled and the spin-dependent xc potential is obtained from a single OEP equation. We discuss the extension of our EXX-OEP implementation within the linearized augmented plane-wave (FLAPW) method and show results for prototype magnetic metals.

TT 60.4   Wed 18:15   Poster A

Electric switchable giant Rashba-type spin splitting in bulk PbS — •Bin Shao[1], Wenhui Duan[2], and Thomas Frauenheim[1] — [1]BCCMS, University of Bremen, Bremen, Germany — [2]Institute for Advanced Study, Tsinghua University, Beijing, China

Realizing electric controllable spin is one of the major challenges in the field of spintronics. A promising approach is to utilize so-called Rashba effect, which arises from the spin-orbit coupling under broken inversion symmetry, leading to a momentum-dependent spin splitting in k-space. However, the sizes of this splitting are usually rather small, which hinders the application of this effect in spintronics. In this work, based on density functional calculation, we predict a giant Rashba-type spin splitting in bulk PbS with space group P6₃mc. The phonon spectrum calculation gives evidence of the thermal stability of this system. The origin of the giant Rashba effect has been demonstrated from the deviation of the S ion from the inversion symmetric position, leading to an ferroelectric polarization along c axis. By switching the direction of the ferroelectric polarization, the spin directions of bulk carriers governed by the Rashba effect are completely rotated, which grants a potential approach to manipulate the spin of electrons by an external electric field. Moreover, under a reasonable hydrostatic pressure, the system could obtain the inversion symmetry due to the movement of the S ion backwards to symmetric positions. As a result, the system turns into a topological phase with the massless Dirac cone state at the (001) surface.

TT 60.5   Wed 18:15   Poster A

GW+fRG: Towards an fRG enhancement of ab initio calculations — Jannis Ehrlich[1,2], Carsten Honerkamp[1], Christoph Friedrich[2], and •Stephan Blügel[2] — [1]Institut für theoretische Festkörperphysik, RWTH Aachen University, D-52056 Aachen, Germany — [2]PGI-1 and IAS-1, FZJ & JARA, D-52425 Jülich, Germany

Spin excitations in solids are of fundamental interest for a wide variety of phenomena. Most materials-specific theoretical studies are based on the adiabatic treatment of the spin-degees of freedom in the context of DFT. Approaches based on the *GW* approximation include screening effects due to charge fluctuations but neglect vertex corrections and other contributions like magnetic fluctuations. The functional renormalization group (fRG) can overcome these limitations as it resums a different class of diagrams, among them charge and magnetic fluctuations and vertex corrections. We discuss how the equations for two-particle vertices in the fRG contain the *GW* approximation, the Bethe-Salpeter equation (BSE) and the parquet approach on certain levels of approximations. Thus, a fRG calculation of materials properties could be a powerful approach to improve the *GW* and BSE methods already applied in first-principles calculations. By using recently suggested channel decomposition schemes [1,2] the method has gained in flexibility and in potential for tackling more complex tasks. Here we propose first steps to develop the fRG approach for the *ab initio* calculation of materials properties.

[1] C. Husemann, M. Salmhofer, Phys. Rev. B **79**, 195125 (2009).
[2] W. Wang *et al.*, Phys. Rev. B **85**, 035414 (2012).

TT 60.6   Wed 18:15   Poster A

The quantum anomalous Hall effect in HgMnTe — •Jan Böttcher, Christoph Kleiner, and Ewelina M. Hankiewicz — Uni Würzburg, Institut für Theoretische Physik und Astrophysik, Germany

Recently, the quantum anomalous Hall (QAH) effect was predicted to exist in Mn doped HgTe. Within the QAH phase only one edge state remains at an edge due to an opposite coupling of spin to the magnetization. The experimental proof is however still outstanding. The paramagnetic nature of the Mn impurities gives rise to the formation of Landau levels which makes it experimentally challenging to distinguish the QAH from a conventional quantum Hall (QH) state. Based on the BHZ model, we present an extended study of the transition from the quantum spin Hall to the QAH state as well as the QAH to the quantum Hall state. For this purpose, we make use of the finite difference method and compare the results with analytical calculations. Hallmarks of the QAH states in the presence of magnetic fields are discussed. The BHZ model has natural limitations in the

high magnetic field regime. We therefore compare our results with band structure calculations based on the 8x8 Kane Hamiltonian. Signatures in the magnetoresistance are discussed which might open the door to distinguish the QAH from the QH state in future transport experiments.

TT 60.7   Wed 18:15   Poster A

Nonconventional screening of the Coulomb interaction in low-dimensional semiconductors and insulators — Ersoy Sasioglu, •Christoph Friedrich, and Stefan Blügel — Peter Grünberg Institut and Institute for Advanced Simulation, Forschungszentrum Jülich and JARA, 52425 Jülich, Germany

Screening effects play a fundamental role in determining the exciton binding energy, electron dynamics, and the effective electron-electron interaction in low-dimensional semiconductors and insulators. Experimental observation of the large exciton binding energies and nonhydrogenic Rydberg series in low-dimensional semiconductors indicate an unusual non-local screening of the Coulomb interaction. By means of first-principles calculations in conjunction with the random-phase approximation (RPA) within the FLAPW method we study the screening of the Coulomb interaction in low-dimensional semiconductors and insulators. For this purpose a novel tetrahedron method has been implemented. We show that the screening in these systems deviates substantially from the bulk behavior, i.e., the screened interaction W cannot be expressed by a simple static dielectric constant. We compare the numerical RPA results to analytical functions derived from image-charge models for the isolated slab and for a repeated slab model. We find a nonconventional screening in low-dimensions. This nonconventional screening explains the deviations from the usual hydrogenic Rydberg series of energy levels of the excitonic states in one- and two-dimensional semiconductors and opens up possibilities for fundamental studies of correlation effects in low-dimensional materials.